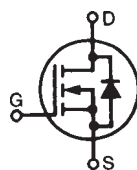


## Polar3™ HiperFET™ Power MOSFET

**IXFT94N30P3**  
**IXFQ94N30P3**  
**IXFH94N30P3**

**$V_{DSS} = 300V$**   
 **$I_{D25} = 94A$**   
 **$R_{DS(on)} \leq 36m\Omega$**

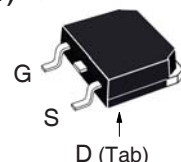
N-Channel Enhancement Mode  
Avalanche Rated  
Fast Intrinsic Rectifier



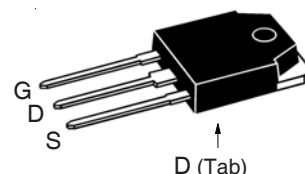
| Symbol     | Test Conditions                                                    | Maximum Ratings |            |
|------------|--------------------------------------------------------------------|-----------------|------------|
| $V_{DSS}$  | $T_J = 25^\circ C$ to $150^\circ C$                                | 300             | V          |
| $V_{DGR}$  | $T_J = 25^\circ C$ to $150^\circ C$ , $R_{GS} = 1M\Omega$          | 300             | V          |
| $V_{GSS}$  | Continuous                                                         | $\pm 20$        | V          |
| $V_{GSM}$  | Transient                                                          | $\pm 30$        | V          |
| $I_{D25}$  | $T_C = 25^\circ C$                                                 | 94              | A          |
| $I_{DM}$   | $T_C = 25^\circ C$ , Pulse Width Limited by $T_{JM}$               | 235             | A          |
| $I_A$      | $T_C = 25^\circ C$                                                 | 47              | A          |
| $E_{AS}$   | $T_C = 25^\circ C$                                                 | 2.5             | J          |
| $dv/dt$    | $I_S \leq I_{DM}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ C$ | 35              | V/ns       |
| $P_D$      | $T_C = 25^\circ C$                                                 | 1040            | W          |
| $T_J$      |                                                                    | -55 ... +150    | $^\circ C$ |
| $T_{JM}$   |                                                                    | 150             | $^\circ C$ |
| $T_{stg}$  |                                                                    | -55 ... +150    | $^\circ C$ |
| $T_L$      | Maximum Lead Temperature for Soldering                             | 300             | $^\circ C$ |
| $T_{SOLD}$ | Plastic Body for 10s                                               | 260             | $^\circ C$ |
| $M_d$      | Mounting Torque (TO-247 & TO-3P)                                   | 1.13 / 10       | Nm/lb.in   |
| Weight     | TO-268                                                             | 4.0             | g          |
|            | TO-3P                                                              | 5.5             | g          |
|            | TO-247                                                             | 6.0             | g          |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ C$ Unless Otherwise Specified) | Characteristic Values |      |                           |
|--------------|---------------------------------------------------------------------|-----------------------|------|---------------------------|
|              |                                                                     | Min.                  | Typ. | Max.                      |
| $BV_{DSS}$   | $V_{GS} = 0V$ , $I_D = 1mA$                                         | 300                   |      | V                         |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 4mA$                                     | 3.0                   |      | 5.0 V                     |
| $I_{GSS}$    | $V_{GS} = \pm 20V$ , $V_{DS} = 0V$                                  |                       |      | $\pm 100$ nA              |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$ , $V_{GS} = 0V$<br>$T_J = 125^\circ C$           |                       |      | 25 $\mu A$<br>750 $\mu A$ |
| $R_{DS(on)}$ | $V_{GS} = 10V$ , $I_D = 0.5 \cdot I_{D25}$ , Note 1                 |                       |      | 36 m $\Omega$             |

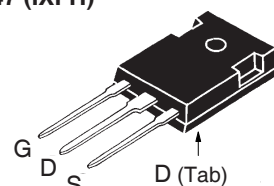
TO-268 (IXFT)



TO-3P (IXFQ)



TO-247 (IXFH)



G = Gate      D = Drain  
S = Source    Tab = Drain

### Features

- Fast Intrinsic Rectifier
- Avalanche Rated
- Low  $R_{DS(ON)}$  and  $Q_G$
- Low Package Inductance

### Advantages

- High Power Density
- Easy to Mount
- Space Savings

### Applications

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- Robotics and Servo Controls

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)                                                                            | Characteristic Values |      |                         |
|--------------|------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|------|-------------------------|
|              |                                                                                                                                                      | Min.                  | Typ. | Max.                    |
| $g_{fs}$     | $V_{DS} = 20\text{V}, I_D = 0.5 \cdot I_{D25}, \text{Note 1}$                                                                                        | 40                    | 68   | S                       |
| $C_{iss}$    | $V_{GS} = 0\text{V}, V_{DS} = 25\text{V}, f = 1\text{MHz}$                                                                                           |                       | 5510 | pF                      |
| $C_{oss}$    |                                                                                                                                                      |                       | 965  | pF                      |
| $C_{rss}$    |                                                                                                                                                      |                       | 25   | pF                      |
| $R_{Gi}$     | Gate Input Resistance                                                                                                                                |                       | 1.2  | $\Omega$                |
| $t_{d(on)}$  | <b>Resistive Switching Times</b><br>$V_{GS} = 10\text{V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$<br>$R_G = 1\Omega \text{ (External)}$ |                       | 23   | ns                      |
| $t_r$        |                                                                                                                                                      |                       | 19   | ns                      |
| $t_{d(off)}$ |                                                                                                                                                      |                       | 49   | ns                      |
| $t_f$        |                                                                                                                                                      |                       | 11   | ns                      |
| $Q_{g(on)}$  | $V_{GS} = 10\text{V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$                                                                           |                       | 102  | nC                      |
| $Q_{gs}$     |                                                                                                                                                      |                       | 33   | nC                      |
| $Q_{gd}$     |                                                                                                                                                      |                       | 37   | nC                      |
| $R_{thJC}$   | (TO-247 & TO-3P)                                                                                                                                     |                       |      | 0.12 $^\circ\text{C/W}$ |
| $R_{thCS}$   |                                                                                                                                                      |                       | 0.25 | $^\circ\text{C/W}$      |

## Source-Drain Diode

| Symbol   | Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)                       | Characteristic Values |      |               |
|----------|-------------------------------------------------------------------------------------------------|-----------------------|------|---------------|
|          |                                                                                                 | Min.                  | Typ. | Max.          |
| $I_S$    | $V_{GS} = 0\text{V}$                                                                            |                       |      | 94 A          |
| $I_{SM}$ | Repetitive, Pulse Width Limited by $T_{JM}$                                                     |                       |      | 376 A         |
| $V_{SD}$ | $I_F = I_S, V_{GS} = 0\text{V}, \text{Note 1}$                                                  |                       |      | 1.5 V         |
| $t_{rr}$ | $I_F = 47\text{A}, -di/dt = 100\text{A}/\mu\text{s}$<br>$V_R = 100\text{V}, V_{GS} = 0\text{V}$ |                       |      | 250 ns        |
| $I_{RM}$ |                                                                                                 |                       | 15.6 | A             |
| $Q_{RM}$ |                                                                                                 |                       | 1.4  | $\mu\text{C}$ |

Note 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

|           |           |           |           |              |              |              |              |              |             |
|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
| 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
| 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

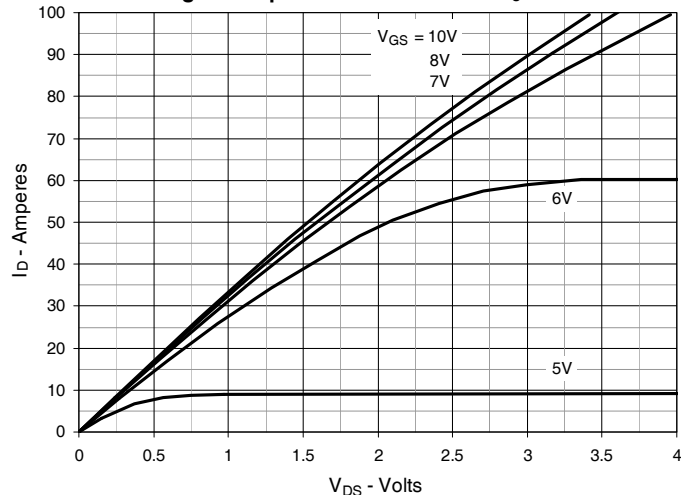
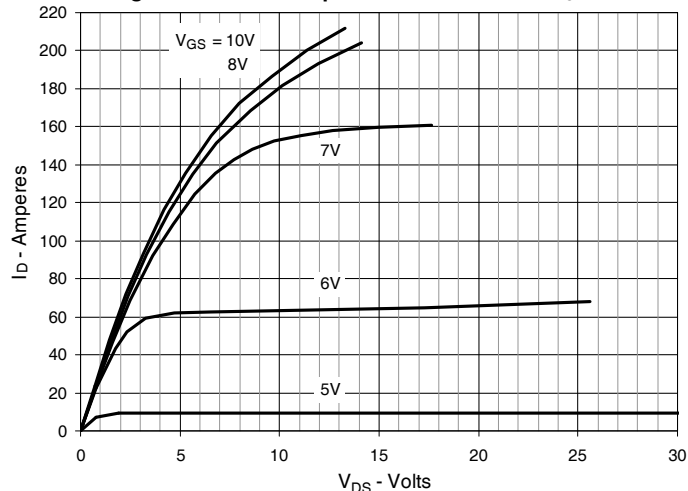
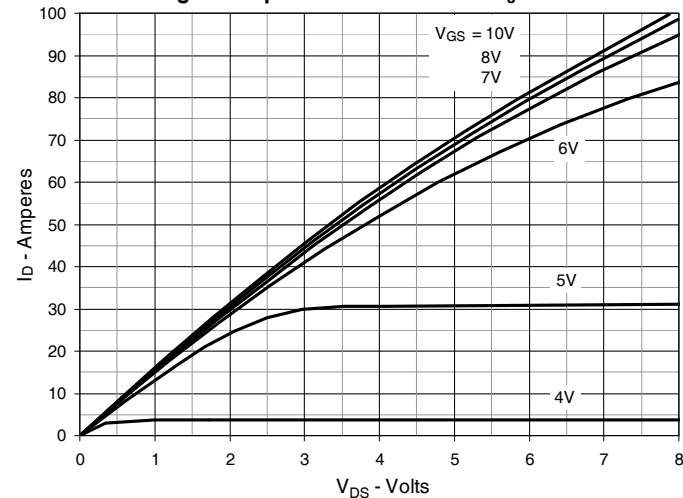
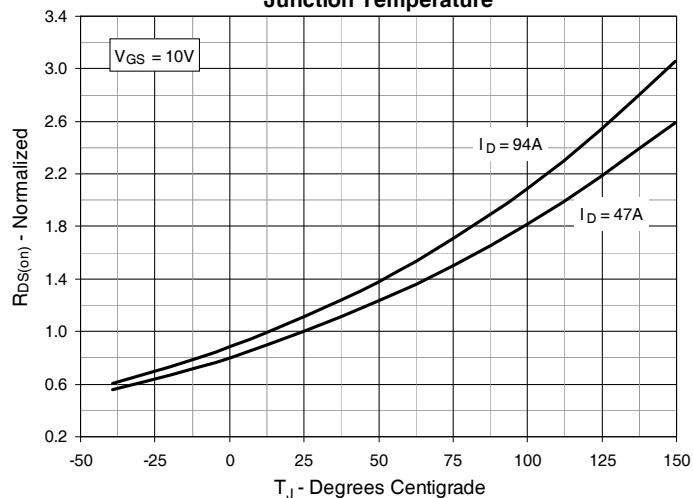
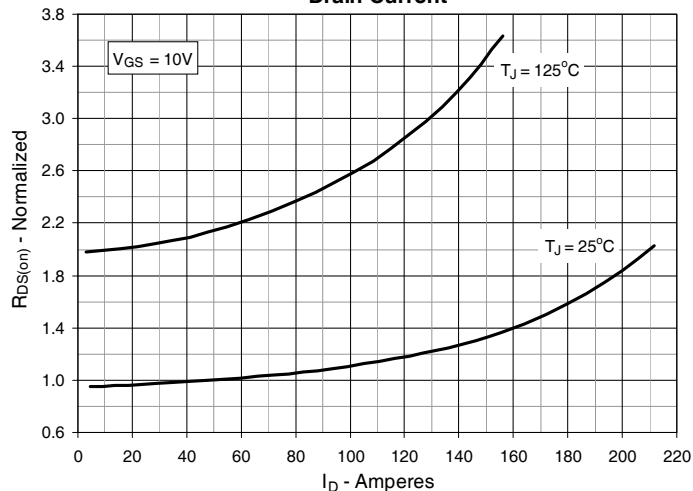
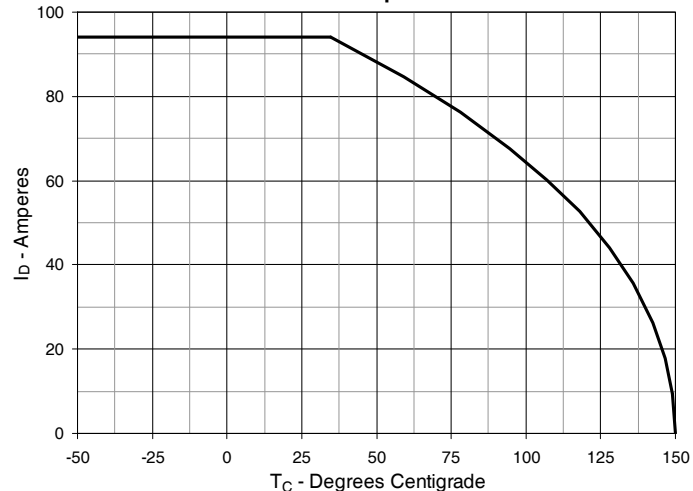
**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$** 

**Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$** 

**Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$** 

**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 47\text{A}$  Value vs. Junction Temperature**

**Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 47\text{A}$  Value vs. Drain Current**

**Fig. 6. Maximum Drain Current vs. Case Temperature**


Fig. 7. Input Admittance

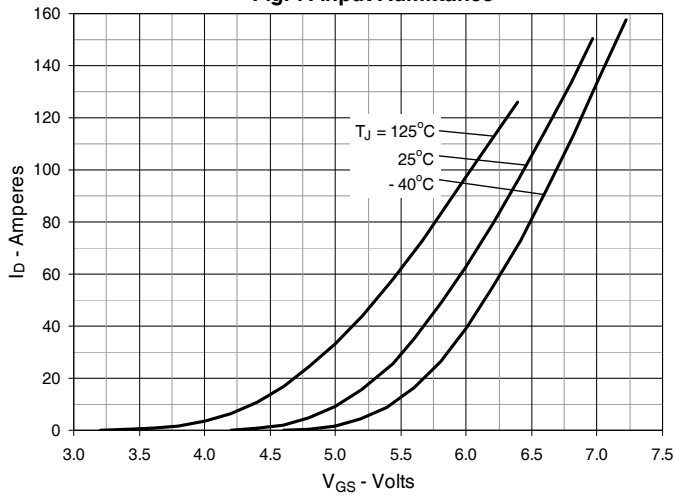


Fig. 8. Transconductance

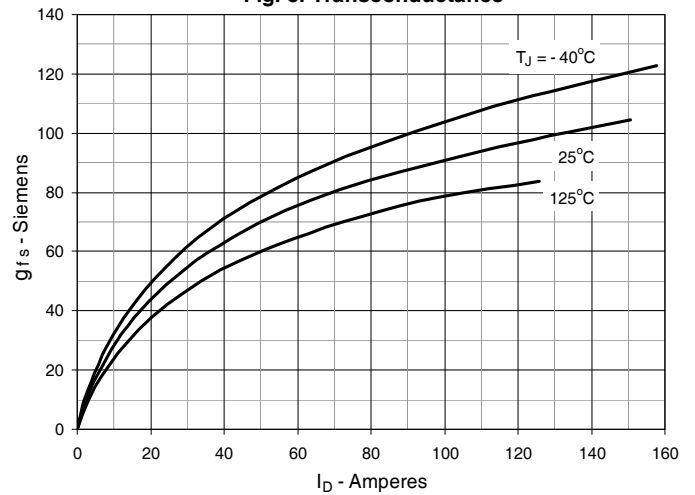


Fig. 9. Forward Voltage Drop of Intrinsic Diode

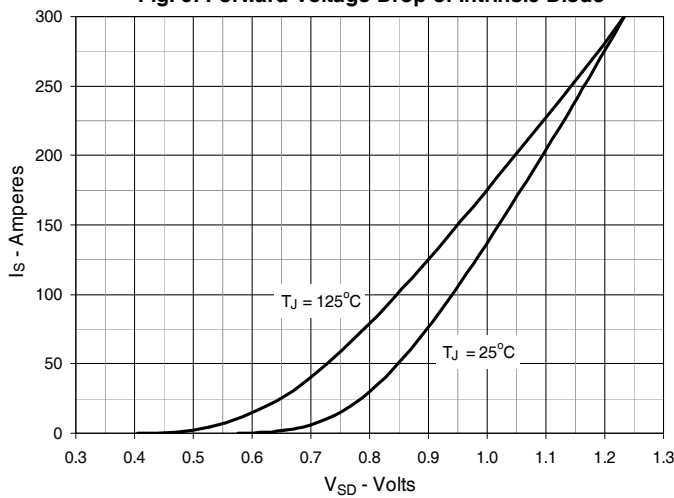


Fig. 10. Gate Charge

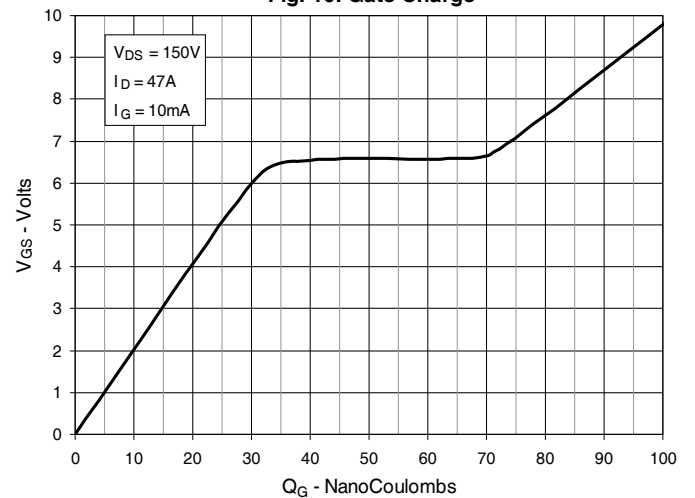


Fig. 11. Capacitance

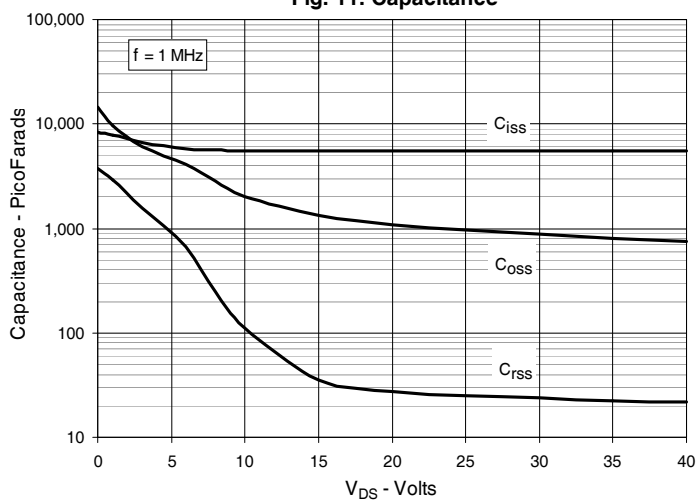


Fig. 12. Forward-Bias Safe Operating Area

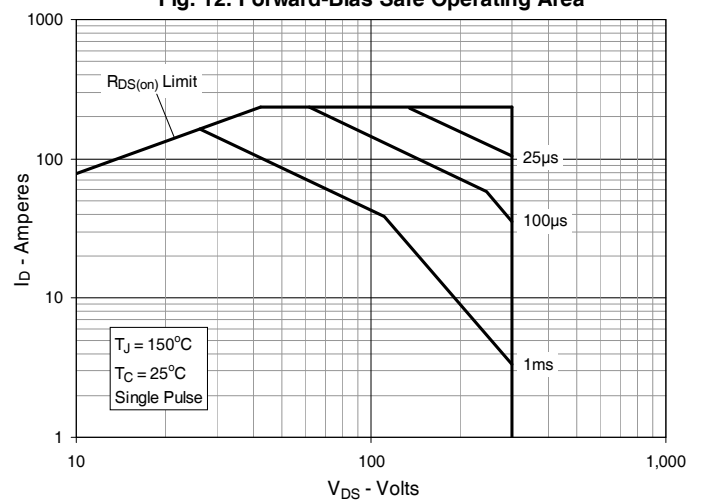
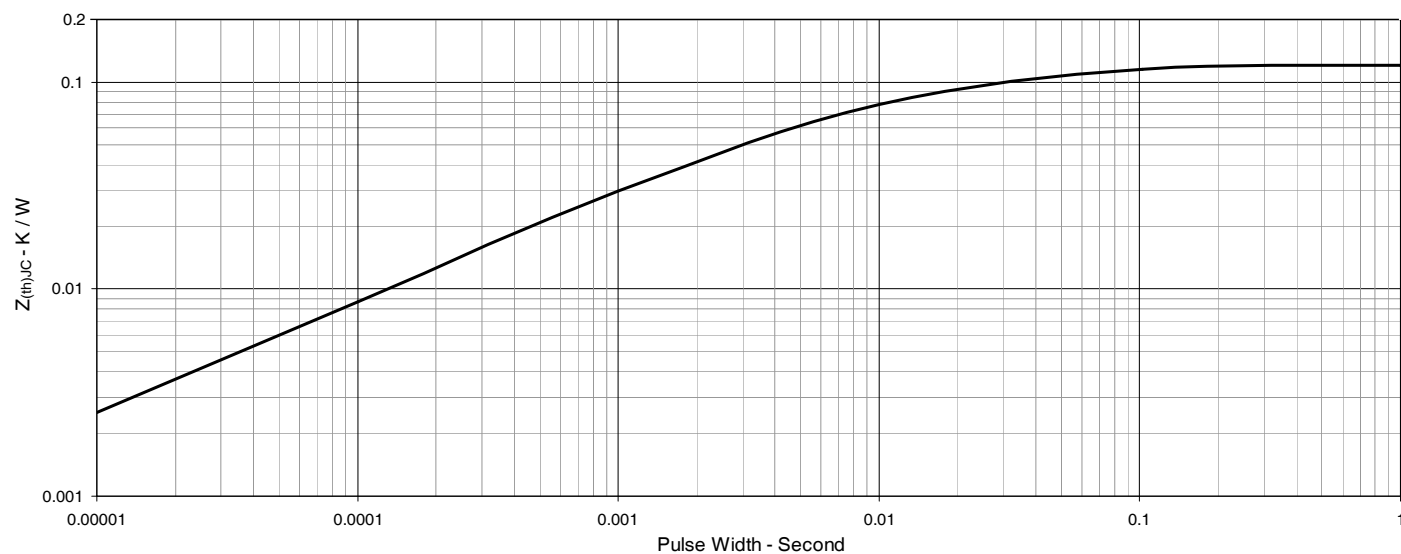
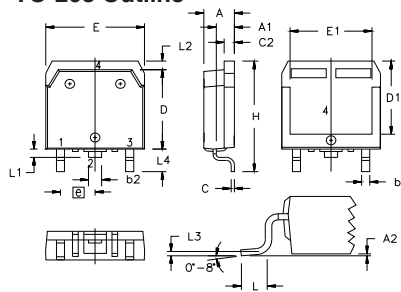


Fig. 13. Maximum Transient Thermal Impedance



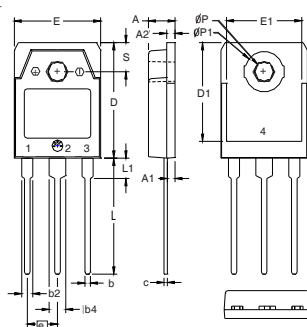
## TO-268 Outline



Terminals: 1 - Gate      2,4 - Drain  
                  3 - Source

| SYM | INCHES   |      | MILLIMETERS |       |
|-----|----------|------|-------------|-------|
|     | MIN      | MAX  | MIN         | MAX   |
| A   | .193     | .201 | 4.90        | 5.10  |
| A1  | .106     | .114 | 2.70        | 2.90  |
| A2  | .001     | .010 | 0.02        | 0.25  |
| B   | .045     | .057 | 1.15        | 1.45  |
| B2  | .073     | .083 | 1.90        | 2.10  |
| C   | .016     | .026 | 0.40        | 0.65  |
| C2  | .543     | .553 | 13.80       | 14.00 |
| D1  | .488     | .500 | 12.40       | 12.70 |
| D   | .604     | .630 | 15.85       | 16.05 |
| E1  | .504     | .535 | 13.30       | 13.60 |
|     | .215 BSC |      | 5.45 BSC    |       |
| H   | .736     | .752 | 18.70       | 19.10 |
| L   | .094     | .106 | 2.40        | 2.70  |
| L1  | .047     | .055 | 1.20        | 1.40  |
| L2  | .039     | .045 | 1.00        | 1.15  |
| L3  | .010 BSC |      | 0.25 BSC    |       |
| L4  | .150     | .161 | 3.80        | 4.10  |

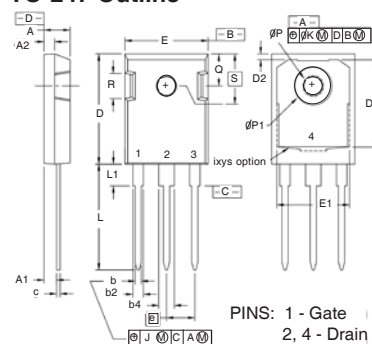
## TO-3P Outline



PINS: 1 - Gate  
2, 4 - Drain  
3 - Source

| SYM | INCHES   |      | MILLIMETERS |       |
|-----|----------|------|-------------|-------|
|     | MIN      | MAX  | MIN         | MAX   |
| A   | .185     | .193 | 4.70        | 4.90  |
| A1  | .051     | .059 | 1.30        | 1.50  |
| A2  | .057     | .065 | 1.45        | 1.65  |
| b   | .035     | .045 | 0.90        | 1.15  |
| b2  | .075     | .087 | 1.90        | 2.20  |
| b4  | .114     | .126 | 2.90        | 3.20  |
| c   | .022     | .031 | 0.55        | 0.80  |
| D   | .780     | .799 | 19.80       | 20.30 |
| D1  | .665     | .677 | 16.90       | 17.20 |
| E   | .610     | .622 | 15.50       | 15.80 |
| E1  | .531     | .539 | 13.50       | 13.70 |
| e   | .215 BSC |      | 5.45 BSC    |       |
| L   | .779     | .795 | 19.80       | 20.20 |
| L1  | .134     | .142 | 3.40        | 3.60  |
| ØP  | .126     | .134 | 3.20        | 3.40  |
| ØP1 | .272     | .280 | 6.90        | 7.10  |
| S   | .193     | .201 | 4.90        | 5.10  |

## TO-247 Outline



PINS: 1 - Gate  
2, 4 - Drain  
3 - Source

| SYM | INCHES   |      | MILLIMETERS |       |
|-----|----------|------|-------------|-------|
|     | MIN      | MAX  | MIN         | MAX   |
| A   | .190     | .205 | 4.83        | 5.21  |
| A1  | .090     | .100 | 2.29        | 2.54  |
| A2  | .075     | .085 | 1.91        | 2.16  |
| b   | .045     | .055 | 1.14        | 1.40  |
| b2  | .075     | .087 | 1.91        | 2.20  |
| b4  | .115     | .126 | 2.92        | 3.20  |
| C   | .024     | .031 | 0.61        | 0.80  |
| D   | .819     | .840 | 20.80       | 21.34 |
| D1  | .650     | .690 | 16.51       | 17.53 |
| D2  | .035     | .050 | 0.89        | 1.27  |
| E   | .620     | .635 | 15.75       | 16.13 |
| E1  | .545     | .565 | 13.84       | 14.35 |
| e   | .215 BSC |      | 5.45 BSC    |       |
| J   | --       | .010 | --          | 0.25  |
| K   | --       | .025 | --          | 0.64  |
| L   | .780     | .810 | 19.81       | 20.57 |
| L1  | .150     | .170 | 3.81        | 4.32  |
| øP  | .140     | .144 | 3.55        | 3.65  |
| øP1 | .275     | .290 | 6.99        | 7.37  |
| Q   | .220     | .244 | 5.59        | 6.20  |
| R   | .170     | .190 | 4.32        | 4.83  |
| S   | .242 BSC |      | 6.15 BSC    |       |

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